NSN 5962-01-112-8587

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-112-8587 **Body Length:** Between 0.772 inches and 0.808 inches **Body Width:** 0.294 inches **Body Height:** 0.120 inches **Maximum Power Dissipation Rating:** 50.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and 3-state output and w/enable and programmable **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 3.0 volts power source **Time Rating Per Chacteristic:** 450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Prom **Memory Capacity:** Unknown **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:**

Fiig:

A458a0

Demilitarization: Yes - demil/mli